

Supplementary Information

Ag₈SnS₆: a new IR Solar Absorber Material with a near Optimal Bandgap

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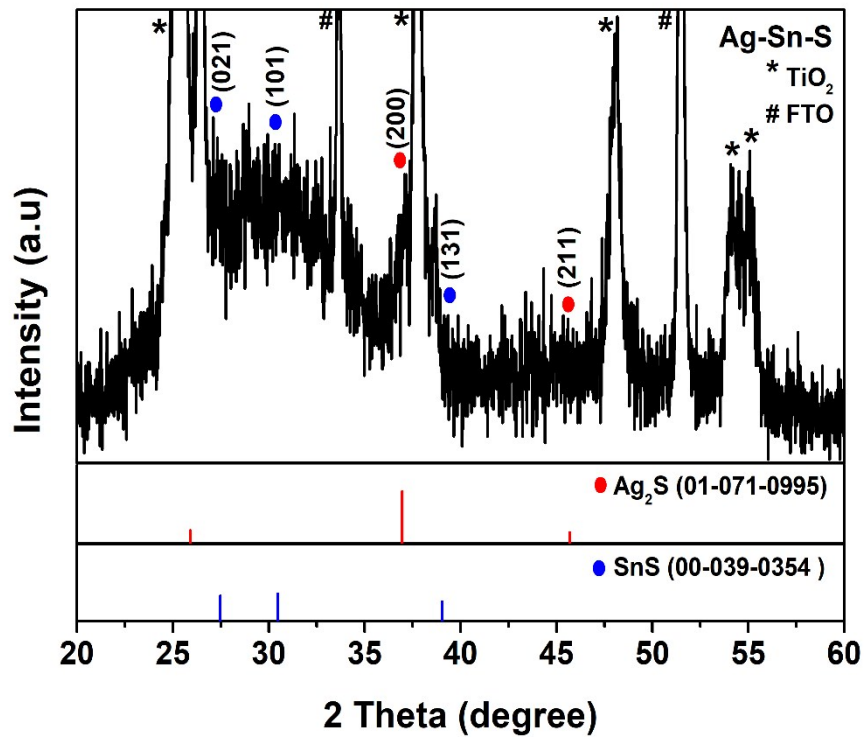


Fig. S1 XRD pattern of Ag-Sn-S sample before heat treatment. The material is mostly amorphous. Only a weak Ag₂S peak at 37° corresponding to the (200) plane is observed.